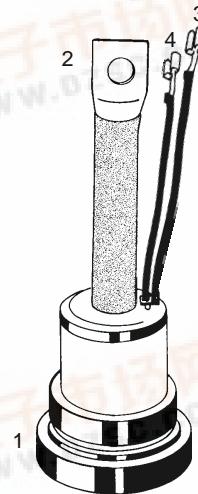
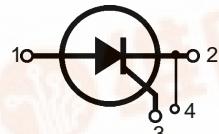


Phase Control Thyristors

$V_{RRM} = 1200-1800 \text{ V}$
 $I_{T(RMS)} = 600 \text{ A}$
 $I_{T(AV)M} = 380 \text{ A}$

V_{RSM}	V_{RRM}	Type
V_{DSM}	V_{DRM}	
V	V	
1300	1200	CS 300-12io3
1700	1600	CS 300-16io3
1900	1800	CS 300-18io3

Not for new application



1 = Anode, 2 = Cathode,
3 = Gate, 4 = Auxiliary Cathode

Symbol	Test Conditions	Maximum Ratings		
$I_{T(RMS)}$	$T_{VJ} = T_{VJM}$	600	A	
$I_{T(AV)M}$	$T_{case} = 85^\circ\text{C}; 180^\circ \text{ sine}$	330	A	
	$T_{case} = 75^\circ\text{C}; 180^\circ \text{ sine}$	380	A	
I_{TSM}	$T_{VJ} = 45^\circ\text{C}; V_R = 0$ $t = 10 \text{ ms (50 Hz), sine}$ $t = 8.3 \text{ ms (60 Hz), sine}$	8500	A	
	$T_{VJ} = T_{VJM}$ $V_R = 0$ $t = 10 \text{ ms (50 Hz), sine}$ $t = 8.3 \text{ ms (60 Hz), sine}$	9000	A	
I^2t	$T_{VJ} = 45^\circ\text{C}$ $V_R = 0$ $t = 10 \text{ ms (50 Hz), sine}$ $t = 8.3 \text{ ms (60 Hz), sine}$	360 000	A^2s	
	$T_{VJ} = T_{VJM}$ $V_R = 0$ $t = 10 \text{ ms (50 Hz), sine}$ $t = 8.3 \text{ ms (60 Hz), sine}$	340 000	A^2s	
$(di/dt)_{cr}$	$T_{VJ} = T_{VJM}$ $f = 50 \text{ Hz}, t_p = 200 \mu\text{s}$ $V_D = 2/3 V_{DRM}$ $I_G = 1 \text{ A}$ $di_G/dt = 1 \text{ A}/\mu\text{s}$	repetitive, $I_T = 1000 \text{ A}$ non repetitive, $I_T = I_{T(AV)M}$	100	$\text{A}/\mu\text{s}$
$(dv/dt)_{cr}$	$T_{VJ} = T_{VJM}; R_{GK} = \infty; \text{method 1 (linear voltage rise)}$	$V_{DR} = 2/3 V_{DRM}$	1000	$\text{V}/\mu\text{s}$
P_{GM}	$T_{VJ} = T_{VJM}$ $I_T = I_{T(AV)M}$	$t_p = 30 \mu\text{s}$ $t_p = 10 \text{ ms}$	120 10	W
V_{RGM}			10	V
T_{VJ}			-40...+125	$^\circ\text{C}$
T_{VJM}			125	$^\circ\text{C}$
T_{stg}			-40...+125	$^\circ\text{C}$
M_d	Mounting torque		3.5 31	Nm lb.in.
Weight			500	g

Features

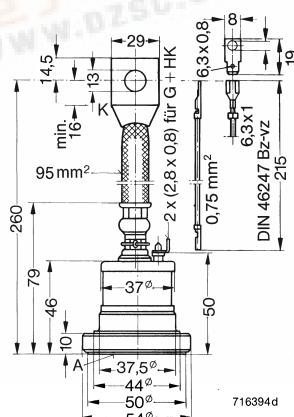
- Thyristor for line frequencies
- International flat base package
- Planar glassivated chip
- Long-term stability of blocking currents and voltages

Applications

- Motor control
- Power converter
- AC power controller

Advantages

- Space and weight savings
- Simple mounting
- Improved temperature and power cycling

Dimensions in mm (1 mm = 0.0394")

Data according to IEC 60747
IXYS reserves the right to change limits, test conditions and dimensions

Symbol	Test Conditions	Characteristic Values		
I_R, I_D	$T_{VJ} = T_{VJM}$; $V_R = V_{RRM}$; $V_D = V_{DRM}$	≤	40	mA
V_T	$I_T = 1000 \text{ A}$; $T_{VJ} = 25^\circ\text{C}$	≤	1.43	V
V_{TO}	For power-loss calculations only ($T_{VJ} = 125^\circ\text{C}$)	1.0		V
r_T		0.43		$\text{m}\Omega$
V_{GT}	$V_D = 6 \text{ V}$; $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = -40^\circ\text{C}$	≤	2.0	V
I_{GT}	$V_D = 6 \text{ V}$; $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = -40^\circ\text{C}$	≤	150	mA
I_{GD}	$T_{VJ} = T_{VJM}$; $V_D = 2/3 V_{DRM}$	≤	0.2	V
		≤	1	mA
I_L	$T_{VJ} = 25^\circ\text{C}$; $t_p = 10 \mu\text{s}$ $I_G = 0.7 \text{ A}$; $di_G/dt = 0.7 \text{ A}/\mu\text{s}$	≤	100	mA
I_H	$T_{VJ} = 25^\circ\text{C}$; $V_D = 6 \text{ V}$; $R_{GK} = \infty$	≤	100	mA
t_{gd}	$T_{VJ} = 25^\circ\text{C}$; $V_D = 1/2 V_{DRM}$ $I_G = 0.7 \text{ A}$; $di_G/dt = 0.7 \text{ A}/\mu\text{s}$	≤	2	μs
t_q	$T_{VJ} = T_{VJM}$; $I_T = 330 \text{ A}$, $t_p = 300 \mu\text{s}$; $di/dt = -20 \text{ A}/\mu\text{s}$ $V_R = 100 \text{ V}$; $dv/dt = 20 \text{ V}/\mu\text{s}$; $V_D = 2/3 V_{DRM}$	typ.	150	μs
R_{thJC}	DC current		0.09	K/W
R_{thJH}	DC current		0.12	K/W
d_s	Creepage distance on surface	1.55		mm
d_A	Strike distance through air	1.55		mm
a	Max. acceleration, 50 Hz	50		m/s^2

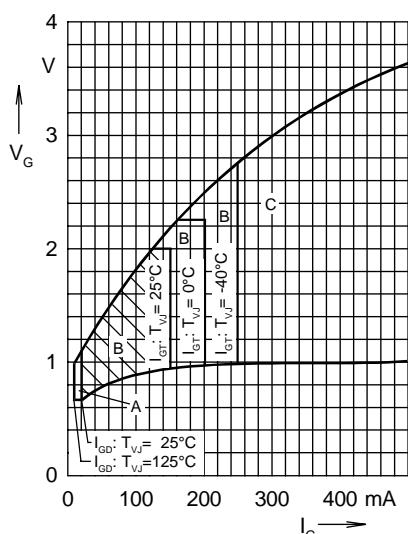


Fig. 1 Gate voltage and gate current
Triggering:
A = no; B = possible; C = safe

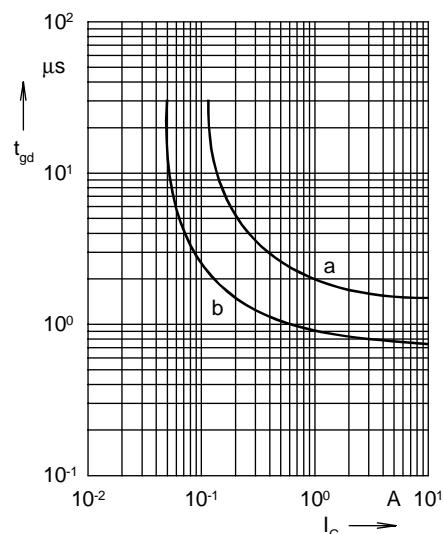


Fig. 2 Gate controlled delay time t_{gd}
a = limit; b = typical

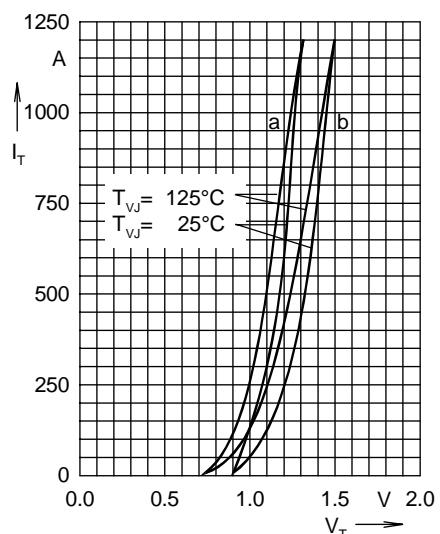


Fig. 3 On-state characteristics
a = typical; b = limit

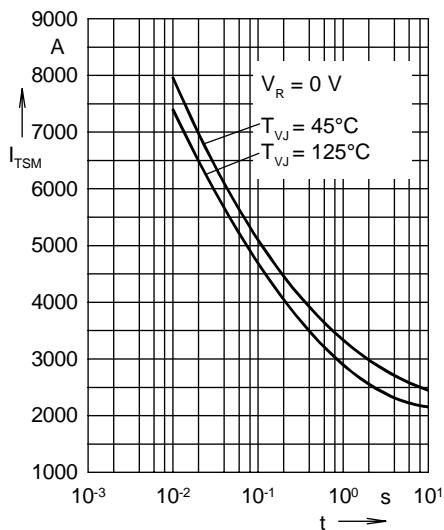


Fig. 4 Surge overload current
 I_{TSM} : crest value, t : duration

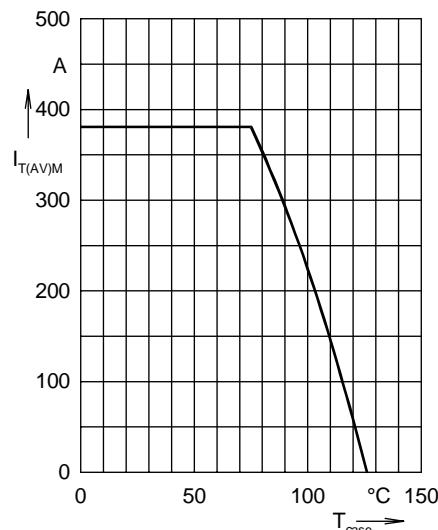


Fig. 5 Maximum forward current at
case temperature 180° sine

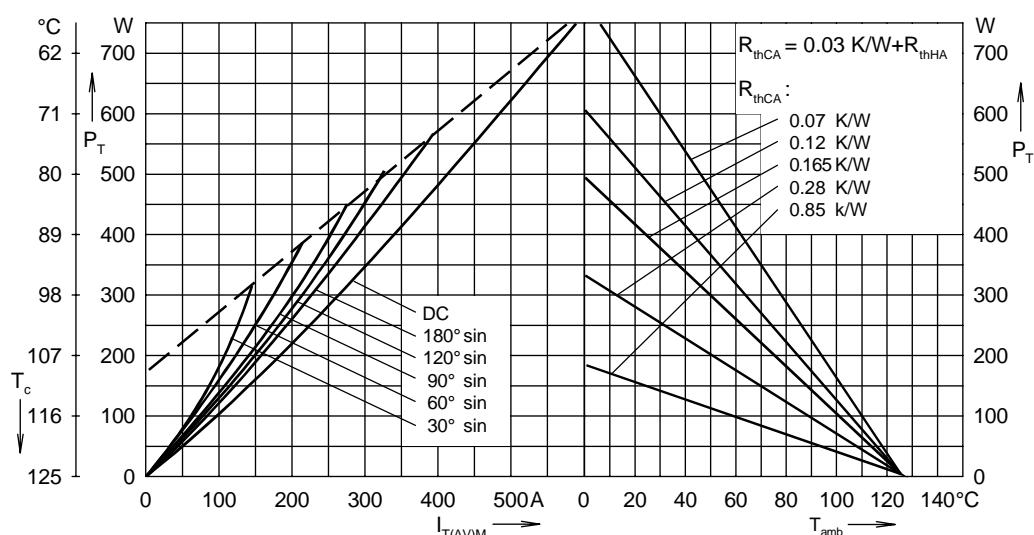


Fig. 6 Power dissipation versus on-state current and ambient temperature (sinusoidal current)

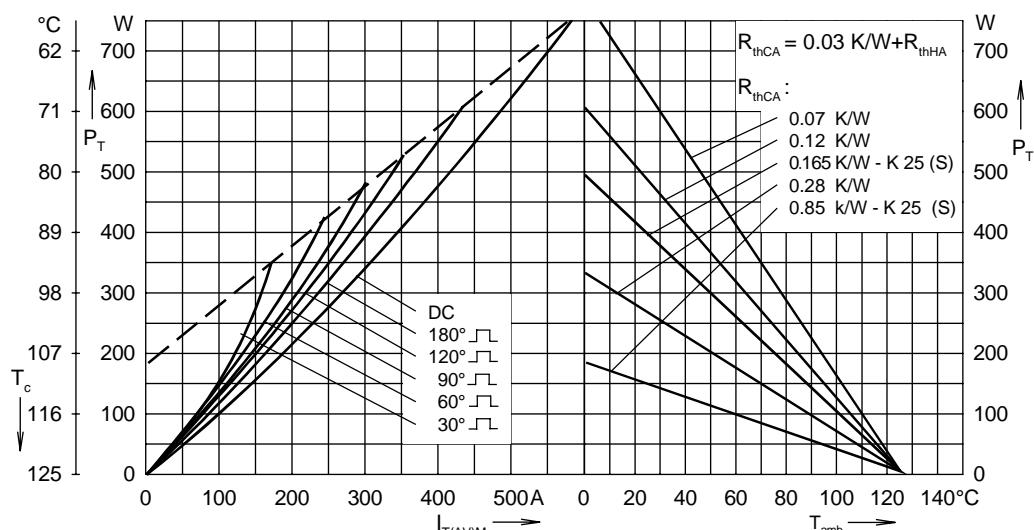


Fig. 7 Power dissipation versus on-state current and ambient temperature (rectangular current)